

TD2

TD 2 / RÉALISER UN ÉTAGE DE PRÉ-AMPLIFICATION

Objectifs pédagogiques

A la fin de cette thématique, les étudiant-e-s seront capables de :

- **lister les paramètres importants** dans le choix d'un amplificateur linéaire intégré
- **définir et exécuter un protocole expérimental** pour :
 - ▷ caractériser un système linéaire, en continu et dans le domaine fréquentiel, incluant un ALI
 - ▷ valider le fonctionnement d'un étage de pré-amplification vis-à-vis d'un cahier des charges (contraintes et performances)
- choisir et mettre en oeuvre une solution analogique adaptée à un cahier des charges pour la mise en forme d'un signal provenant d'un capteur ou d'un autre système

Activités pédagogiques

- Lectures (hors temps présentiel - en ligne)
 - ▷ Fiche résumé : Amplificateur Linéaire Intégré / Principe et montages de base
- Séance de **TD2**
- Séance de **TP2** (module TP CéTI)

Ressources Complémentaires

- Fiche résumé : Amplificateur Linéaire Intégré / Principe et montages de base
- Fiche résumé : Amplificateur Linéaire Intégré / Modélisation 1er ordre et rebouclage
- Exercices supplémentaires proposés sur eCampus (avec correction)

Exercice 1 - Amplificateur Linéaire Intégré TL081**Notions abordées**

- ▷ paramètres importants d'un ALI
- ▷ relation entre la sortie et les entrées

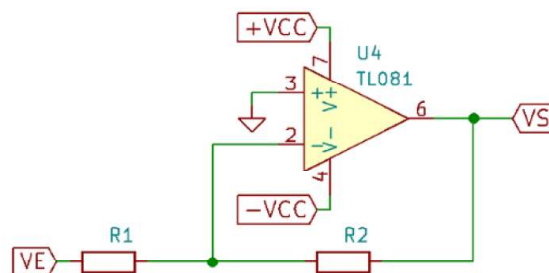
On fournit en annexe une partie de la documentation technique de l'amplificateur linéaire intégré (ALI) **TL081**.

1. Cherchez dans la documentation les valeurs des paramètres électriques suivants :
 - (a) Tension d'alimentation (Supply Voltage)
 - (b) Tension d'entrée différentielle maximale
 - (c) Amplification différentielle
 - (d) Gain unitaire ou produit gain-bande-passante
 - (e) Impédance d'entrée
 - (f) Slew Rate
2. Précisez à quoi correspond chacun de ces paramètres.
3. Rappelez la relation entre les entrées V^+ , V^- et la sortie V_S d'un ALI.
4. Tracez la caractéristique $V_S = f(\varepsilon)$ où $\varepsilon = (V^+ - V^-)$ pour cet ALI avec $V_{CC} = 15\text{ V}$.
5. Est-ce un bon amplificateur ? Quelle est sa bande-passante ?

Exercice 2 - Amplificateur inverseur**Notions abordées**

- ▷ montage amplificateur inverseur

On se propose d'étudier à présent le montage suivant :

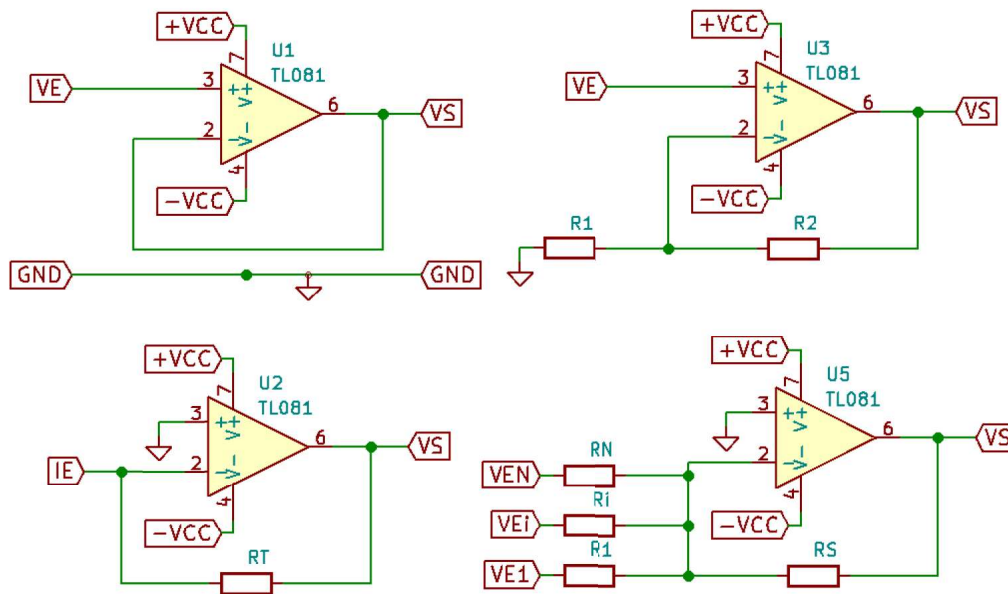


1. Donnez la relation entre V_S et V_E du circuit précédent en utilisant la relation d'entrées-sortie de l'exercice 1.
2. Quelle hypothèse fait-on souvent lorsqu'on utilise des ALI avec une rétroaction négative ?
3. Quelle relation trouve-t-on alors entre V_S et V_E en partant de cette hypothèse ?
4. Cette hypothèse est-elle justifiée ?

Exercice 3 - Structures amplificatrices**Notions abordées**

- ▷ montage amplificateur inverseur

On s'intéresse aux montages suivants, autour d'amplificateurs linéaires intégrés.



Donnez les relations entre les grandeurs de sortie (V_S), les grandeurs d'entrée (V_E ou I_E) et des différents éléments des montages autour de U1, U2, U3 et U5.

Exercice 4 - Montage amplificateur

Notions abordées

▷ conception d'un circuit amplificateur

On souhaite réaliser, à partir d'amplificateur linéaire intégré de type TL081, un système ayant les performances suivantes :

- gain dans la bande-passante : 27 dB
- bande-passante de : 400 kHz

Proposez une solution.

TL08xx JFET-Input Operational Amplifiers

1 Features

- Low Power Consumption: 1.4 mA/ch Typical
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias Current: 30 pA Typical
- Low Input Offset Current: 5 pA Typical
- Output Short-Circuit Protection
- Low Total Harmonic Distortion: 0.003% Typical
- High Input Impedance: JFET Input Stage
- Latch-Up-Free Operation
- High Slew Rate: 13 V/μs Typical
- Common-Mode Input Voltage Range Includes V_{CC+}

2 Applications

- Tablets
- White goods
- Personal electronics
- Computers

3 Description

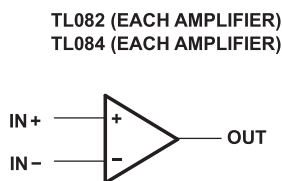
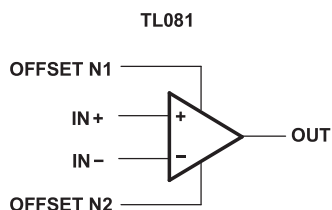
The TL08xx JFET-input operational amplifier family is designed to offer a wider selection than any previously developed operational amplifier family. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit. The devices feature high slew rates, low input bias and offset currents, and low offset-voltage temperature coefficient.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|------------|--------------------|
| TL084xD | SOIC (14) | 8.65 mm × 3.91 mm |
| TL08xxFK | LCCC (20) | 8.89 mm × 8.89 mm |
| TL084xJ | CDIP (14) | 19.56 mm × 6.92 mm |
| TL084xN | PDIP (14) | 19.3 mm × 6.35 mm |
| TL084xNS | SO (14) | 10.3 mm × 5.3 mm |
| TL084xPW | TSSOP (14) | 5.0 mm × 4.4 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Schematic Symbol



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|--|------------------------------|--------|--|------|
| V _{CC+} | Supply voltage ⁽²⁾ | | | 18 | V |
| V _{CC-} | | | | -18 | |
| V _{ID} | Differential input voltage ⁽³⁾ | | | ±30 | V |
| V _I | Input voltage ⁽²⁾⁽⁴⁾ | | | ±15 | V |
| | Duration of output short circuit ⁽⁵⁾ | | | Unlimited | |
| | Continuous total power dissipation | | | See Dissipation Rating Table | |
| T _A | Operating free-air temperature | TL08_C TL08_AC TL08_BC | 0 | 70 | °C |
| | | TL08_I | -40 | 85 | |
| | | TL084Q | -40 | 125 | |
| | | TL08_M | -55 | 125 | |
| | Operating virtual junction temperature | | | 150 | °C |
| T _C | Case temperature for 60 seconds | FK package | TL08_M | 260 | °C |
| | Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | J or JG package | TL08_M | 300 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
- (3) Differential voltages are at IN+, with respect to IN-.
- (4) The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
- (5) The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

6.2 ESD Ratings

| | | VALUE | UNIT |
|--------------------|-------------------------|--|------|
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | 1000 |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | 1500 |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|------------------|---------------------|--------|----------------------|----------------------|------|
| V _{CC+} | Supply voltage | | 5 | 15 | V |
| V _{CC-} | Supply voltage | | -5 | -15 | V |
| V _{CM} | Common-mode voltage | | V _{CC-} + 4 | V _{CC+} - 4 | V |
| T _A | Ambient temperature | TL08xM | -55 | 125 | °C |
| | | TL08xQ | -40 | 125 | |
| | | TL08xI | -40 | 85 | |
| | | TL08xC | 0 | 70 | |

Electrical Characteristics for TL08xC, TL08xxC, and TL08xl (continued)

 $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | $T_A^{(1)}$ | TL081C, TL082C, TL084C | | | TL081AC, TL082AC, TL084AC | | | TL081BC, TL082BC, TL084BC | | | TL081I, TL082I, TL084I | | | UNIT |
|-----------------|---------------------------------|---------------------|------------------------|-----|-----|---------------------------|-----|-----|---------------------------|-----|-----|------------------------|-----|-----|------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| I_{CC} | Supply current (each amplifier) | $V_O = 0$, No load | 25°C | 1.4 | 2.8 | 1.4 | 2.8 | | 1.4 | 2.8 | | 1.4 | 2.8 | | mA |
| V_{O1}/V_{O2} | Crosstalk attenuation | $A_{VD} = 100$ | 25°C | 120 | | 120 | | | 120 | | | 120 | | | dB |

6.6 Electrical Characteristics for TL08xM and TL084x

 $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS ⁽¹⁾ | T_A | TL081M, TL082M | | | TL084Q, TL084M | | | UNIT |
|-----------------|---|---|----------------|-----------|------------|----------------|------------|-----|------------------------------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_{IO} | Input offset voltage | $V_O = 0$, $R_S = 50\ \Omega$ | 25°C | 3 | 6 | 3 | 9 | | mV |
| | | | Full range | | 9 | | 15 | | |
| α_{VIO} | Temperature coefficient of input offset voltage | $V_O = 0$, $R_S = 50\ \Omega$ | Full range | 18 | | 18 | | | $\mu\text{V}/^\circ\text{C}$ |
| I_{IO} | Input offset current ⁽²⁾ | $V_O = 0$ | 25°C | 5 | 100 | 5 | 100 | | pA |
| | | | 125°C | 20 | | 20 | | | nA |
| I_{IB} | Input bias current ⁽²⁾ | $V_O = 0$ | 25°C | 30 | 200 | 30 | 200 | | pA |
| | | | 125°C | 50 | | 50 | | | nA |
| V_{ICR} | Common-mode input voltage range | 25°C | ± 11 | -12 to 15 | | ± 11 | -12 to 15 | | V |
| V_{OM} | Maximum peak output voltage swing | $R_L = 10\text{ k}\Omega$ | 25°C | ± 12 | ± 13.5 | ± 12 | ± 13.5 | | V |
| | | $R_L \geq 10\text{ k}\Omega$ | Full range | ± 12 | | ± 12 | | | |
| | | $R_L \geq 2\text{ k}\Omega$ | | ± 10 | ± 12 | ± 10 | ± 12 | | |
| A_{VD} | Large-signal differential voltage amplification | $V_O = \pm 10\text{ V}$, $R_L \geq 2\text{ k}\Omega$ | 25°C | 25 | 200 | 25 | 200 | | V/mV |
| | | | Full range | 15 | | 15 | | | |
| B_1 | Unity-gain bandwidth | 25°C | | 3 | | 3 | | | MHz |
| r_i | Input resistance | 25°C | | 10^{12} | | 10^{12} | | | Ω |
| CMRR | Common-mode rejection ratio | $V_{IC} = V_{ICRmin}$, $V_O = 0$, $R_S = 50\ \Omega$ | 25°C | 80 | 86 | 80 | 86 | | dB |
| k_{SVR} | Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$) | $V_{CC} = \pm 15\text{ V}$ to $\pm 9\text{ V}$, $V_O = 0$, $R_S = 50\ \Omega$ | 25°C | 80 | 86 | 80 | 86 | | dB |
| I_{CC} | Supply current (each amplifier) | $V_O = 0$, No load | 25°C | 1.4 | 2.8 | 1.4 | 2.8 | | mA |
| V_{O1}/V_{O2} | Crosstalk attenuation | $A_{VD} = 100$ | 25°C | 120 | | 120 | | | dB |

(1) All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified.

(2) Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive, as shown in Figure 13. Pulse techniques must be used that maintain the junction temperatures as close to the ambient temperature as possible.

6.7 Operating Characteristics

 $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|---|------------------|-----|-----|------------------|
| SR | $V_I = 10\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 19 | 8 ⁽¹⁾ | 13 | | V/ μs |
| | $V_I = 10\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, $T_A = -55^\circ\text{C}$ to 125°C , See Figure 19 | 5 ⁽¹⁾ | | | |

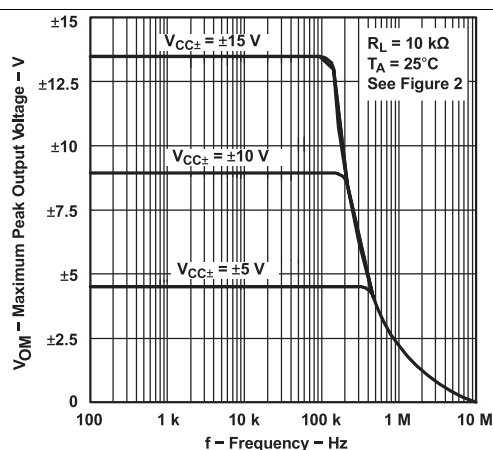
(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.9 Typical Characteristics

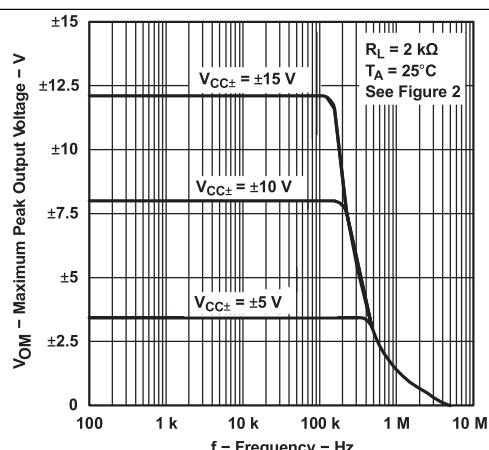
Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. The Figure numbers referenced in the following graphs are located in [Parameter Measurement Information](#).

Table 1. Table of Graphs

| | | | Figure |
|----------|---|--|--|
| V_{OM} | Maximum peak output voltage | versus Frequency versus Free-air temperature versus Load resistance versus Supply voltage | Figure 1, Figure 2, Figure 3 Figure 4 Figure 5 Figure 6 |
| A_{VD} | Large-signal differential voltage amplification | versus Free-air temperature versus Load resistance | Figure 7 Figure 8 |
| | Differential voltage amplification | versus Frequency with feed-forward compensation | Figure 9 |
| P_D | Total power dissipation | versus Free-air temperature | Figure 10 |
| I_{CC} | Supply current | versus Free-air temperature versus Supply voltage | Figure 11 Figure 12 |
| I_{IB} | Input bias current | versus Free-air temperature | Figure 13 |
| | Large-signal pulse response | versus Time | Figure 14 |
| V_O | Output voltage | versus Elapsed time | Figure 15 |
| CMRR | Common-mode rejection ratio | versus Free-air temperature | Figure 16 |
| V_n | Equivalent input noise voltage | versus Frequency | Figure 17 |
| THD | Total harmonic distortion | versus Frequency | Figure 18 |



**Figure 1. Maximum Peak Output Voltage
vs
Frequency**



**Figure 2. Maximum Peak Output Voltage
vs
Frequency**